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LM195/LM395 Ultra Reliable Power Transistors

General Description

The LM195/LM395 are fast, monolithic power integrated circuits with complete overload protection. These devices, which act as high gain power transistors, have included on the chip, current limiting, power limiting, and thermal overload protection making them virtually impossible to destroy from any type of overload. In the standard TO-3 transistor power package, the LM195 will deliver load currents in excess of 1.0A and can switch 40V in 500 ns.

The inclusion of thermal limiting, a feature not easily available in discrete designs, provides virtually absolute protection against overload. Excessive power dissipation or inadequate heat sinking causes the thermal limiting circuitry to turn off the device preventing excessive heating.

The LM195 offers a significant increase in reliability as well as simplifying power circuitry. In some applications, where protection is unusually difficult, such as switching regulators, lamp or solenoid drivers where normal power dissipation is low, the LM195 is especially advantageous.

The LM195 is easy to use and only a few precautions need be observed. Excessive collector to emitter voltage can destroy the LM195 as with any power transistor. When the device is used as an emitter follower with low source impedance, it is necessary to insert a 5.0k resistor in series with the base lead to prevent possible emitter follower oscillations. Although the device is usually stable as an emitter follower, the resistor eliminates the possibility of trouble without degrading performance. Finally, since it has good high frequency response, supply bypassing is recommended.

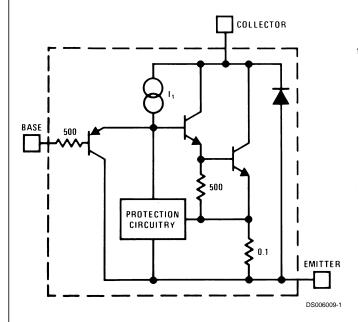
For low-power applications (under 100 mA), refer to the LP395 Ultra Reliable Power Transistor.

The LM195/LM395 are available in the standard TO-3, Kovar TO-5, and TO-220 packages. The LM195 is rated for operation from -55°C to +150°C and the LM395 from 0°C to +125°C.

Features

- Internal thermal limiting
- Greater than 1.0A output current
- 3.0 µA typical base current
- 500 ns switching time
- 2.0V saturation
- Base can be driven up to 40V without damage
- Directly interfaces with CMOS or TTL
- 100% electrical burn-in

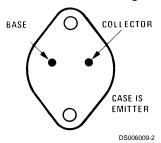
Simplified Circuit



1.0 Amp Lamp Flasher V⁺ 12V R1 10k R2 150k R2 150k R2 150k R3 47k R3 47k R3 BULB DS006009-16

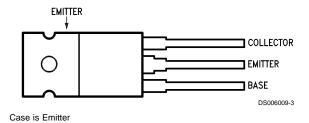
Connection Diagrams

TO-3 Metal Can Package



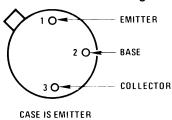
Bottom View Order Number LM195K/883 See NS Package Number K02A (Note 5)

TO-220 Plastic Package



Top View Order Number LM395T See NS Package Number T03B

TO-5 Metal Can Package



DS006009-4

Bottom View Order Number LM195H/883 See NS Package Number H03B (Note 5)

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Collector to Emitter Voltage	
LM195	42V
LM395	36V
Collector to Base Voltage	
LM195	42V
LM395	36V
Base to Emitter Voltage (Forward)	
LM195	42V
LM395	36V

Base to Emitter Voltage (Reverse)	20V
Collector Current	Internally Limited
Power Dissipation	Internally Limited
Operating Temperature Range	
LM195	-55°C to +150°C
LM395	0°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature	
(Soldering, 10 sec.)	260°C

Preconditioning

100% Burn-In In Thermal Limit

Electrical Characteristics

(Note 2)

Parameter	Conditions		LM195		LM395			Units
		Min	Тур	Max	Min	Тур	Max	
Collector-Emitter Operating Voltage			42			36	V	
(Note 4)								
Base to Emitter Breakdown Voltage	$0 \le V_{CE} \le V_{CEMAX}$	42			36	60		V
Collector Current								
TO-3, TO-220	V _{CE} ≤ 15V	1.2	2.2		1.0	2.2		Α
TO-5	V _{CE} ≤ 7.0V	1.2	1.8		1.0	1.8		Α
Saturation Voltage	I _C ≤ 1.0A, T _A = 25°C		1.8	2.0		1.8	2.2	V
Base Current	$0 \le I_C \le I_{MAX}$	3.0 5.0			3.0	10		
	$0 \le V_{CE} \le V_{CEMAX}$		3.0 3.0		3.0		10	μA
Quiescent Current (I _Q)	V _{be} = 0		2.0			2.0	10	mA
	$0 \le V_{CE} \le V_{CEMAX}$					2.0	10	IIIA
Base to Emitter Voltage	$I_C = 1.0A, T_A = +25^{\circ}C$		0.9			0.9		V
Switching Time	$V_{CE} = 36V, R_{L} = 36\Omega,$		500			500		no
	$T_A = 25^{\circ}C$		300			300		ns
Thermal Resistance Junction to	TO-3 Package (K)		2.3	3.0		2.3	3.0	°C/W
Case (Note 3)	TO-5 Package (H)		12	15		12	15	°C/W
	TO-220 Package (T)					4	6	°C/W

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: Unless otherwise specified, these specifications apply for $-55^{\circ}C \le T_{j} \le +150^{\circ}C$ for the LM195 and $0^{\circ}C \le +125^{\circ}C$ for the LM395.

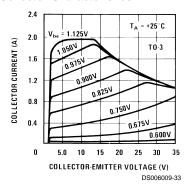
Note 3: Without a heat sink, the thermal resistance of the TO-5 package is about +150°C/W, while that of the TO-3 package is +35°C/W.

Note 4: Selected devices with higher breakdown available.

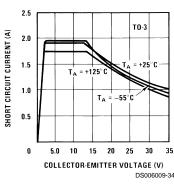
Note 5: Refer to RETS195H and RETS195K drawings of military LM195H and LM195K versions for specifications.

Typical Performance Characteristics (for K and T Packages)

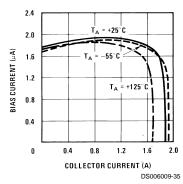
Collector Characteristics



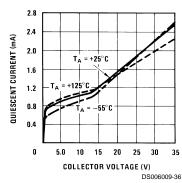
Short Circuit Current



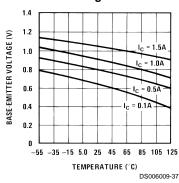
Bias Current



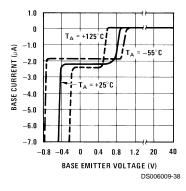
Quiescent Current



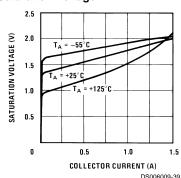
Base Emitter Voltage



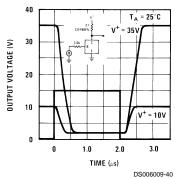
Base Current



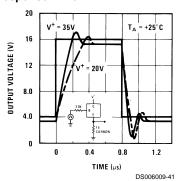
Saturation Voltage



Response Time

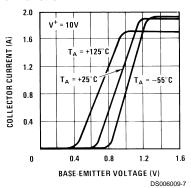


Response Time

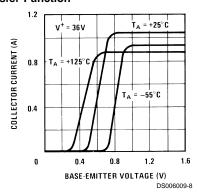


Typical Performance Characteristics (for K and T Packages) (Continued)

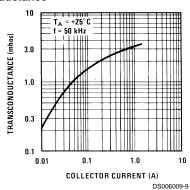
10V Transfer Function



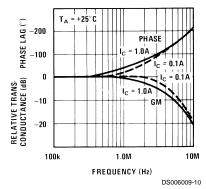
36V Transfer Function

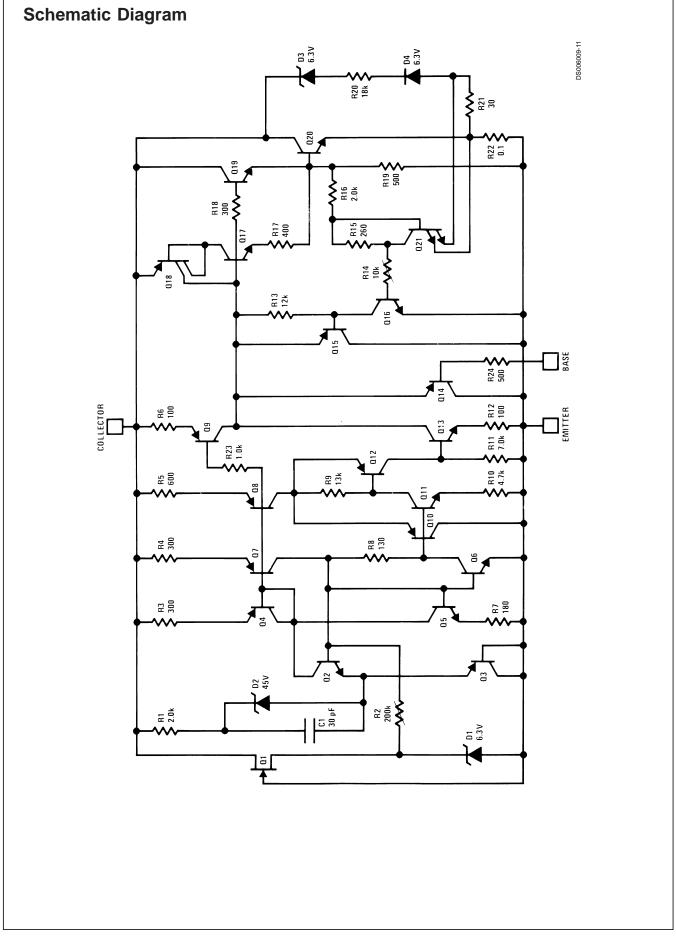


Transconductance



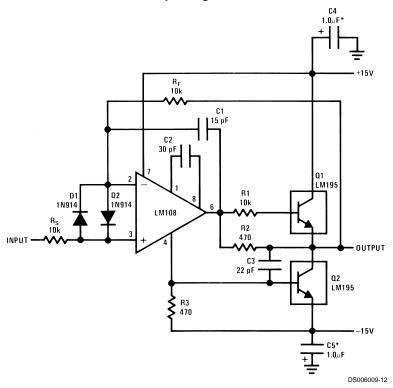
Small Signal Frequency Response



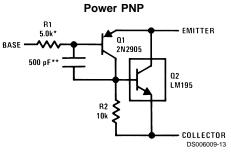


Typical Applications

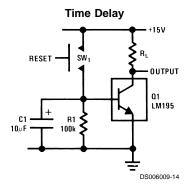
1.0 Amp Voltage Follower

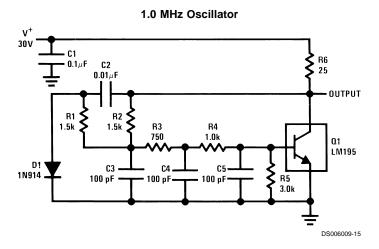


*Solid Tantalum



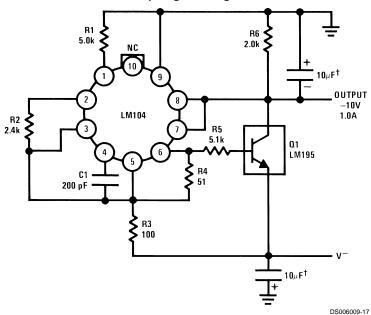
- *Protects against excessive base drive
- **Needed for stability





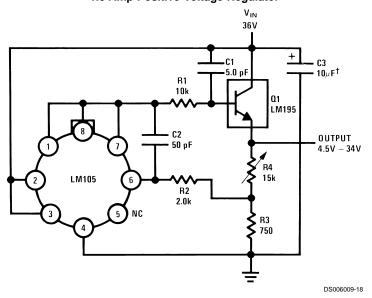
7

1.0 Amp Negative Regulator



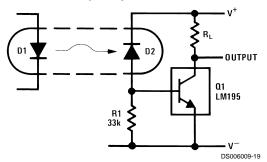
†Solid Tantalum

1.0 Amp Positive Voltage Regulator

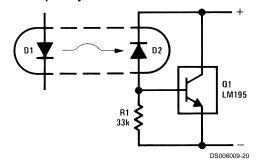


†Solid Tantalum

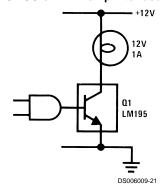
Fast Optically Isolated Switch



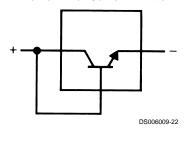
Optically Isolated Power Transistor

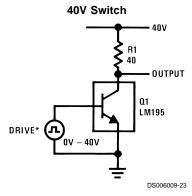


CMOS or TTL Lamp Interface



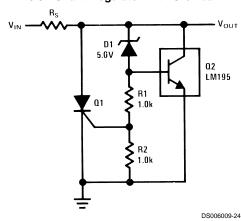
Two Terminal Current Limiter



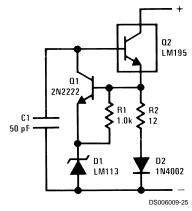


*Drive Voltage 0V to \geq 10V \leq 42V

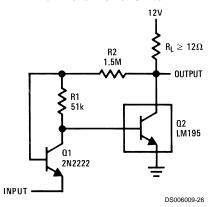
6.0V Shunt Regulator with Crowbar



Two Terminal 100 mA Current Regulator



Low Level Power Switch

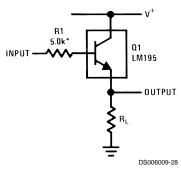


Turn ON = 350 mV Turn OFF = 200 mV

Power One-Shot

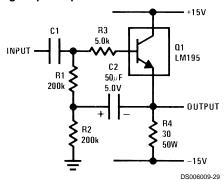
T = R1C R2 = 3R1 $R2 \le 82k$

Emitter Follower

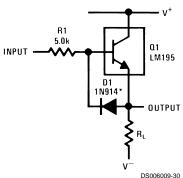


*Need for Stability

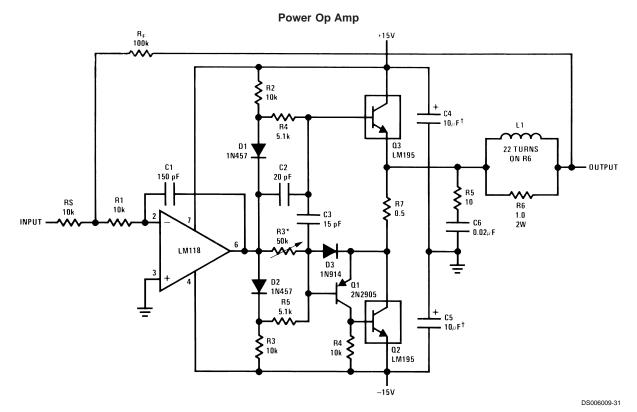
High Input Impedance AC Emitter Follower



Fast Follower



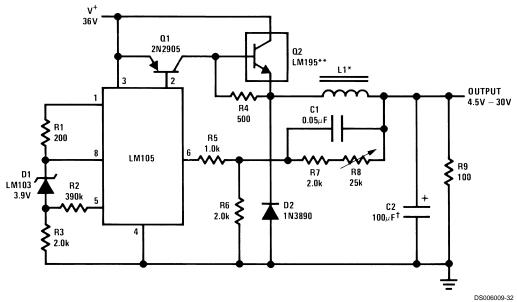
*Prevents storage with fast fall time square wave drive



*Adjust for 50 mA quiescent current

†Solid Tantalum

6.0 Amp Variable Output Switching Regulator

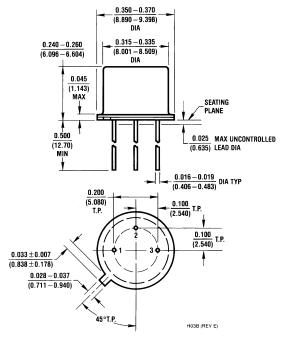


*Sixty turns wound on Arnold Type A-083081-2 core.

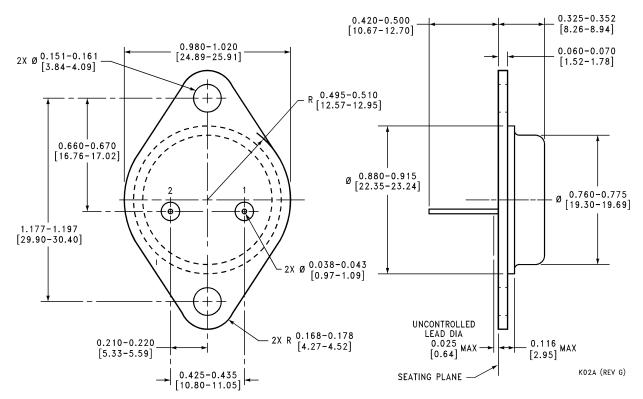
^{**}Four devices in parallel

[†]Solid tantalum

Physical Dimensions inches (millimeters) unless otherwise noted

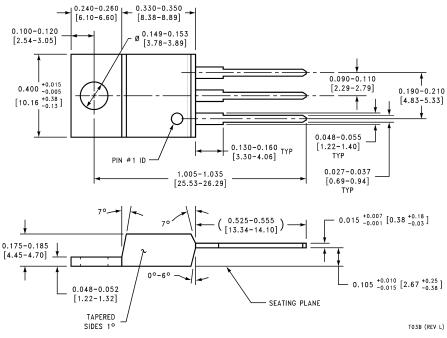


TO-5 Metal Can Package Order Number LM195H/883 NS Package Number H03B



TO-3 Metal Can Package Order Number LM195K/883 NS Package Number K02A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



TO-220 Plastic Package **Order Number LM395T NS Package Number T03B**

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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LM395 Product Folder

Ultra Reliable Power Transistor

General Description	<u>Features</u>	<u>Datasheet</u>	<u>Package</u> <u>& Models</u>	<u>Samples</u> <u>& Pricing</u>	<u>Application</u> <u>Notes</u>

Parametric Table Parametric Table

Function Ultra Reliable Power Transistor

Datasheet

	Title	Size in Kbytes	Date	Viev	v Online	Download	Receive via Email
- 1	LM195 LM395 Ultra Reliable Power Transistors	420 Kbytes	23-Aug-00	View	<u>Online</u>	<u>Download</u>	Receive via Email

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Package Availability, Models, Samples & Pricing

Part Number	Pa	ckage	•	Status	Models		Models		Models		Samples & Electronic	Th				Std Pack	Package Marking
Number	Туре	Pins	MSL		SPICE	IBIS	Orders	Qty	\$US each	Size	Marking						
LM395T	TO 220	3	MSL	Full production	N/A	N/A	Buy Now	1K+	\$1.4900	rail of 45	[logo]¢U¢Z¢2¢T LM395T						
LM395 MDC		<u>Die</u>		Full production	N/A	N/A	Samples			tray of N/A	-						
LM395 MWC	<u>w</u>	<u>Vafer</u>		Full production	N/A	N/A				wafer jar of N/A	-						

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Application Notes

Title	Size in Kbytes	Date	View Online	Download	Receive via Email
AN-110: Application Note 110 Fast IC Power Transistor with Thermal Protection	333 Kbytes	1- May- 98	View Online	Download	Receive via Email
AN-161: IC Voltage Reference has 1 ppm per Degree Drift	133 Kbytes	4- Nov- 95	View Online	Download	Receive via Email
AN-173: IC Zener Eases Reference Design	77 Kbytes	4- Nov- 95	View Online	Download	Receive via Email
AN-181: Application Note 181 3-Terminal Regulator Is Adjustable	123 Kbytes	8- Nov- 00	View Online	Download	Receive via Email

AN-262: Applying Dual and Quad FET Op Amps	177 Kbytes	10- May- 96	View Online	Download	Receive via Email
AN-293: Control Applications of CMOS DACs	178 Kbytes	4- Nov- 95	View Online	Download	Receive via Email
AN-460: LM34/LM35 Precision Monolithic Temperature Sensors	190 Kbytes	4- Nov- 95	View Online	Download	Receive via Email
LM34/LM35 Precision Monolithic Temperature Sensors (JAPANESE)	322 Kbytes		View Online	Download	Receive via
LB-28: Linear Brief 28 General Purpose Power Supply	45 Kbytes	1- May- 98	View Online	Download	Receive via Email

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[Information as of 5-Aug-2002]

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LM195 Product Folder

Ultra Reliable Power Transistor

<u>General</u>	Features	Datasheet	<u>Package</u>	<u>Samples</u>	<u>Application</u>
<u>Description</u>	reatures	Datasileet	<u>& Models</u>	<u>& Pricing</u>	<u>Notes</u>

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LM195 LM395 Ultra Reliable Power Transistors	420 Kbytes	23-Aug-00	View Online	Download	Receive via Email
LM195 Mil-Aero Datasheet MNLM195-H	14 Kbytes		View Online	Download	Receive via Email
LM195 Mil-Aero Datasheet MNLM195-K	9 Kbytes		View Online	Download	Receive via Email

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Package Availability, Models, Samples & Pricing

Part Number	Pa	Package		Status	Models		Samples & Electronic	Pricing		Std Pack	Package Marking
Number	Type	Pins	MSL		SPICE	IBIS	Orders	Qty	\$US each	Size	<u>marking</u>
5962- 8777801XA	TO-39	3	MSL	Full production	N/A	N/A	Buy Now	50+	\$16.0000	tray of 20	[logo] ¢Z¢S¢4¢A LM195H/883Q¢M 5962-8777801XA \$E
5962- 8777801YA	<u>TO-3</u>	2	MSL	Full production	N/A	N/A	Buy Now	50+	\$19.2000	tray of 50	[logo] ¢Z¢S¢4¢A LM195K/883 Q¢M\$E5962- 8777801YA
LM195K MD8		<u>Die</u>		Full production	N/A	N/A	Samples			tray of N/A	-
LM195H MD8	<u></u>	<u>Wafer</u>		Full production	N/A	N/A				wafer jar of N/A	-

LM195H MW8	Wafer	Full production	N/A	N/A	wafe jar of N/A	-
LM195K MW8	Wafer	Full production	N/A	N/A	wafe jar of N/A	-

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Application Notes

Title	Size in Kbytes	Date	View Online	Download	Receive via Email

AN-110: Application Note 110						
Fast IC Power Transistor with	333 Kbytes	1-May-98	View Online	Download	Receive via Email	
Thermal Protection						

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